







Light DM search with TESSERACT

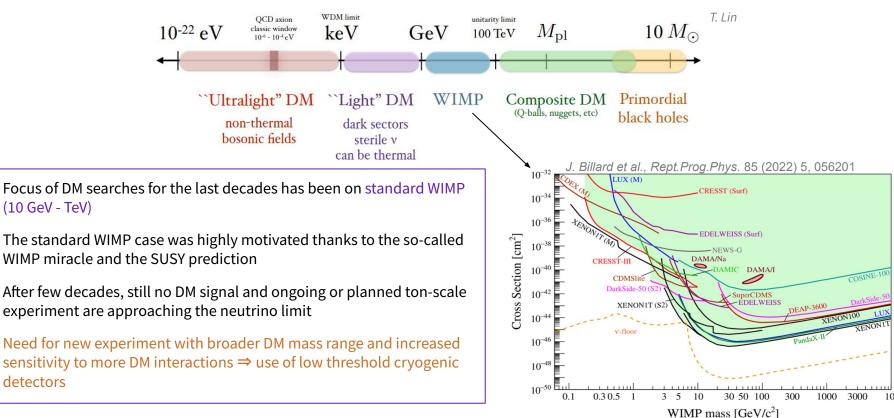
Paul Vittaz, IP2I - CNRS



Bi-national conference on detectors R&D - 29/11/2025

Motivations

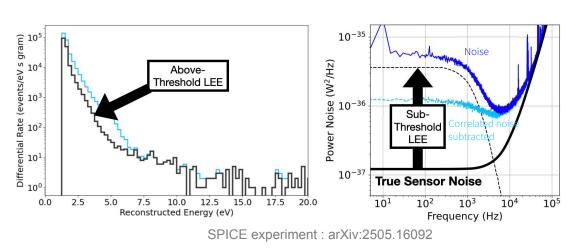
DM candidates: 50 orders of magnitudes in mass

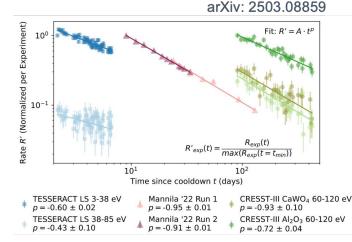




Low Energy Excess

- Currently, all cryogenic experiment which have reached sub keV threshold are seeing a Low Energy Excess (LEE) limiting their DM search (between 10⁶ and 10⁸ evt/kg/keV/day at 100 eV recoil energy)
- LEE represent both the largely <u>dominating background</u> at the lowest energies **AND** the noise limiting our phonon <u>baseline energy resolution</u>
- LEE characteristics: time dependant, non ionising ("Phonon Only"), dependance with holder/vibrations (?)





TESSERACT: Proposed experiment at LSM

Transition Edge Sensor with Sub-Ev Resolution And Cryogenic Targets



























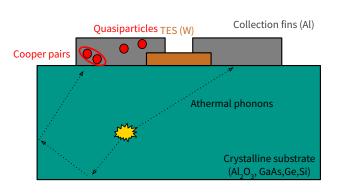
- Target: extend the DM search window from meV to GeV with ultra-low threshold cryogenic detectors, using:
 - o sub-eV energy thresholds
 - background rejection capabilities
 - o diverse target materials with diverse DM couplings
 - ultra quiet underground cryogenic infrastructure at LSM
- Design driver:
 - o find the origin of LEE to mitigate it
 - develop technologies that can reject it

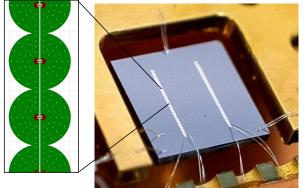




TESSERACT: New generation TES phonon sensors

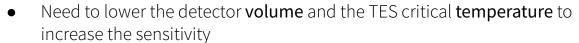
arXiv:2503.03683v2



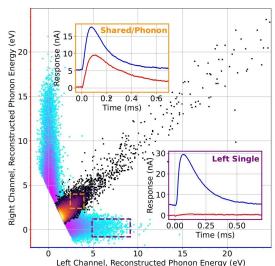


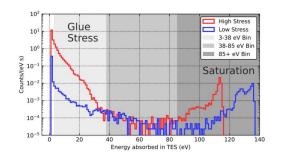
$$\sigma_E \propto V_{det}^{1/2} T_c^3$$

1 cm² x 1 mm (Si)



- LEE mitigation : Low-stress holder ⇒ detector suspended by Al wires
- Background discrimination: Use of two TES channels ⇒ remove sensor stress-induced events (single channel events)

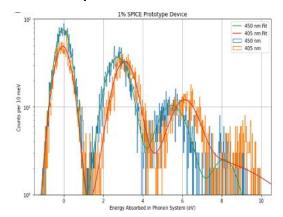




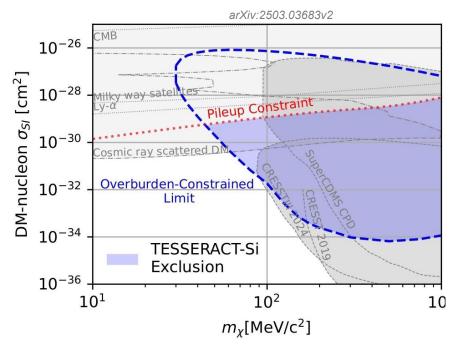


TESSERACT: New generation TES phonon sensors

Proof of concept: 1st DM limit from above-ground detector



- World leading 258.5 meV baseline resolution leading to eV-scale threshold already achieved with a 0.2 g Si detector and T = 50 mK: arXiv:2505.16092v2
- Dark Matter limit published : arXiv:2503.03683v2
- Targeted Tc around 15-20 mK recently achieved

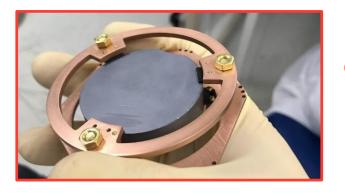


SPICE (Sub-eV Polar Interaction Cryogenic Experiment)

Sapphire (Al₂O₃):

- Sapphire supports many optical phonon modes (~ 100 meV)
- Optical phonons kinematically well-matched to low-mass DM → effective energy transfer
- Coupling to E&M-like inputs due to electric dipole → dark photon sensitivity
- LEE mitigation: Use of two TES-channels to suppress sensor induced LEE

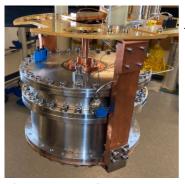




GaAs:

- Polar crystal & bandgap well matched to kinematic region of low mass DM
- Background discrimination using phonon/photon ratio
- LEE mitigation: Photon-phonon coincidence

HeRALD (Helium Roton Apparatus for Light Dark Matter)



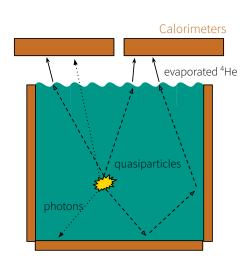
R. Anthony-Petersen et al., arXiv:2307.11877

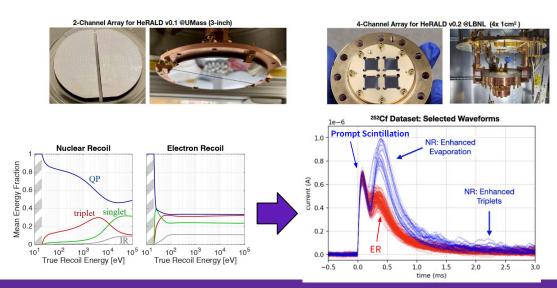
Target : Liquid He

- Light material ⇒ better kinematic matching with LDM
- Extremely radiopure
- No internal stress nor dislocation (LEE source?)
- Superfluid ⇒ no vibrational coupling with the environment (another LEE source ?)
- Several signal channels ⇒ particle identification through pulse shape discrimination

 $m_{\perp} = 1 \text{ GeV/c}^2$

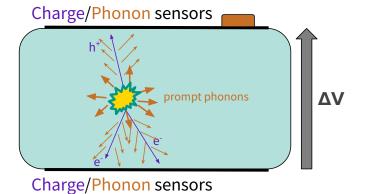
LEE mitigation: multichannel evaporation readout to reject LEE via coincidences

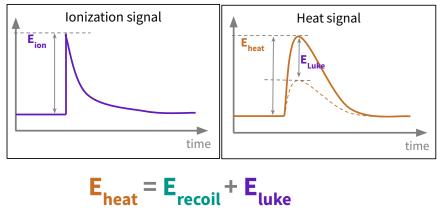




Ge/Si semiconductors

Based on EDELWEISS and Ricochet expertise





$$= \mathbf{E}_{\text{recoil}} + \mathbf{E}_{\text{ion}} \Delta \mathbf{V} / \mathbf{\epsilon}_{\text{eh}}$$



- Two channels: heat and ionization
- Luke boost \Rightarrow additional phonons proportional to ΔV



Two working modes: High Voltage (HV) and Low Voltage (LV)



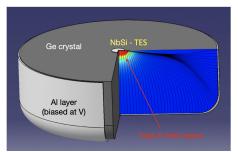
Ge/Si semiconductors HV

High-Voltage approach for optimal ERDM sensitivity

$$E_{\text{heat}} = E_{\text{recoil}} + E_{\text{ion}} \Delta V / \epsilon_{\text{eh}}$$

$$E_{\text{heat}} = E_{\text{ion}} \Delta V / \epsilon_{\text{eh}} \quad (HV)$$



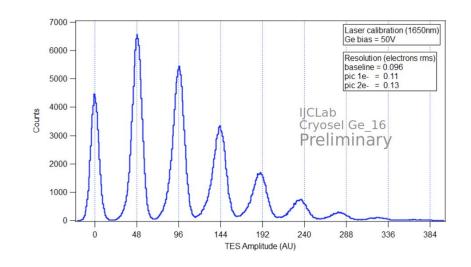


First observation of a single-electron sensitivity in a massive (40g) Ge cryogenic detector!

Low-imp. TES and SQUID readout: 0.1 electron/hole (RMS)

For TESSERACT:

- High control of IR backgrounds and charge leakage
- LEE discrimination down to single e/h pair
- Exquisite sensitivities to ERDM with LEE discrimination

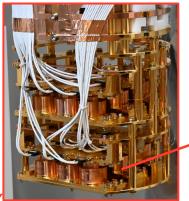


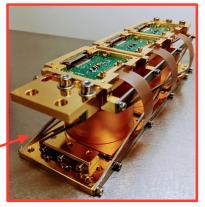
Ge/Si semiconductors LV

Low-Voltage approach for optimal NRDM sensitivity

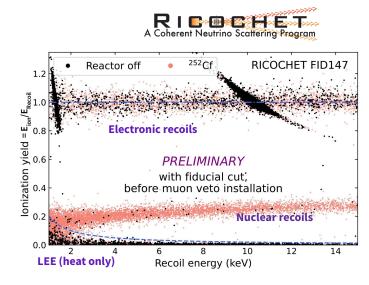
Decades of expertise from **EDELWEISS** and **Ricochet** experiments in dual phonon-ionization readout with cryogenic detectors







Ricochet CryoCube technology: 18 Ge detectors



- Double readout heat/ionization ⇒ particle identification
- 30 eVph and 30 eVee (RMS) @ ILL
- LEE are non ionizing ⇒ improving the charge resolution is of major importance

Ge/Si semiconductors LV

Low-Voltage approach for optimal NRDM sensitivity

Ricochet Cryocube

• Looking for : CENNS

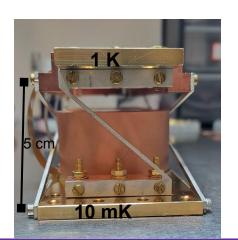
• Phonon sensor: NTD-Ge

• Payload: 18 x 40 g

Total capacitance ~45 pF

• $\sigma_{\text{ion}} \sim 30 - 40 \text{ eVee}$

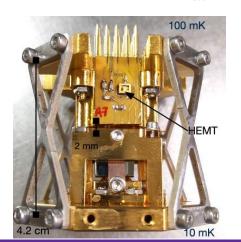
• $\sigma_{\text{heat}}^{\text{lon}} \sim 30 \text{ eVph}$

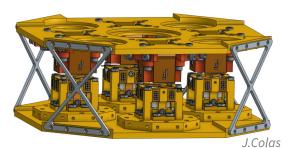


TESSERACT



- Looking for : DM
- Phonon sensor : NTD-Ge ⇒ TES
- Payload: 4 x 5 g (1 cm³)
- Total capacitance ~5 pF





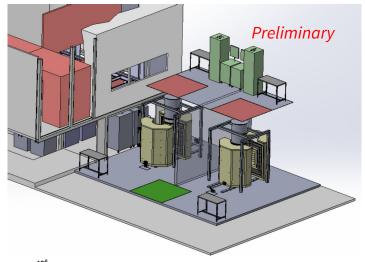
R&D ongoing ...

FRANCE



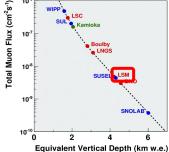


TESSERACT : Proposal for an installation in the *Laboratoire Souterrain de Modane* (LSM)



TESSERACT Integration at LSM

- Two copies of the setup, for enabling both:
 - o underground R&D and detector optimisation
 - o DM science data taking in parallel
- Each detector technologies is designed to achieve major breakthrough in short time scales (few months) hence allowing fast turnarounds
- Targeted background levels < 5 evt/kg/keV/day
- The two setups will be in LSM between 2028 for first DM science data in 2029



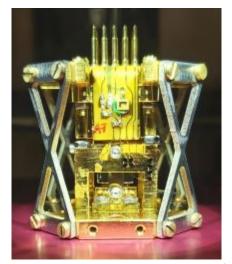
- * LSM (Laboratoire Souterrain de Modane): deepest site in Europe, 4800 m.w.e, 5 μ/m²/day
- Clean room + deradonized air
- PE and lead shielding
- Selection of radiopure materials



Conclusion

TESSERACT @ LSM

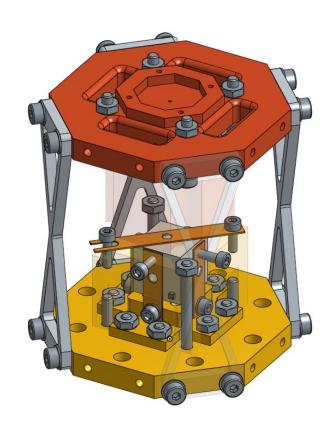
- Different cryogenic targets (Si, Ge, Al₂O₃, GaAs, He) to look for several types of interaction and DM masses
- Multiple signal channels and coincidence-based background rejection to reject LEE and other backgrounds
- Sub-eV phonon energy resolution
- LSM ultra-low background environnement



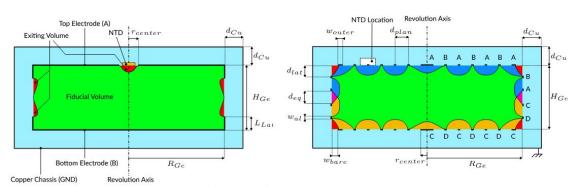


Thank you for your attention

Questions?



Low-Voltage approach for optimal particle identification (Ricochet style bolometer)



PL 38



Salagnac & al: arXiv:2111.12438

FID 38



• Incomplete charge coll. < 10 %

• Fiducial volume: 96 %

Surface event rejection : NO

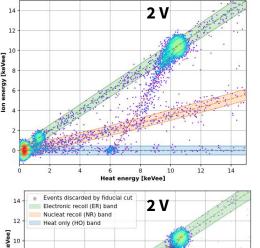
Total capacitance: 15 pF

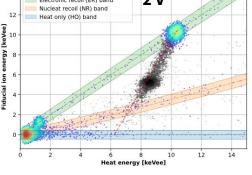
• Incomplete charge coll. < 1 %

• Fiducial volume : **62** %

Surface event rejection : YES

Total capacitance: 18 pF







Shielding

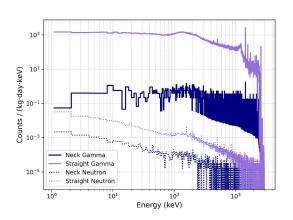
Designed around commercial cryostat and vertical layout.

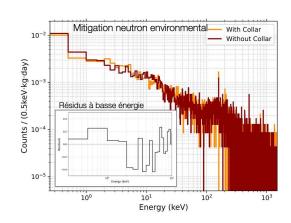
- Narrow 'neck' region, with Pb plug above at 1K
- Thick Cu at base temperature surrounds target region.

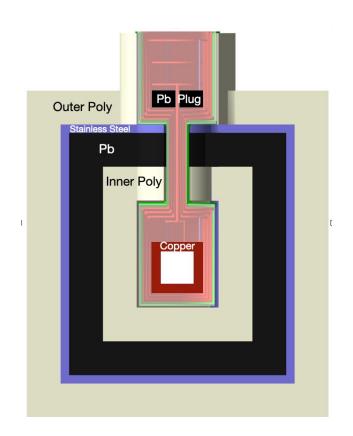
Material screening at LSM ongoing

Simulations predict ~1 DRU (ER) < 1e-3 DRU (NR)

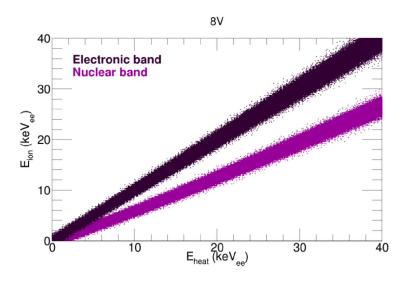
(possible future upgrade: cold inner veto)

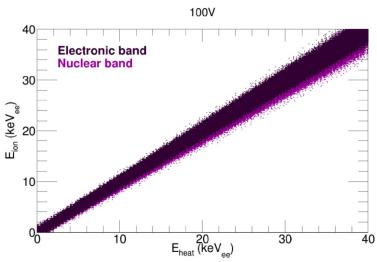






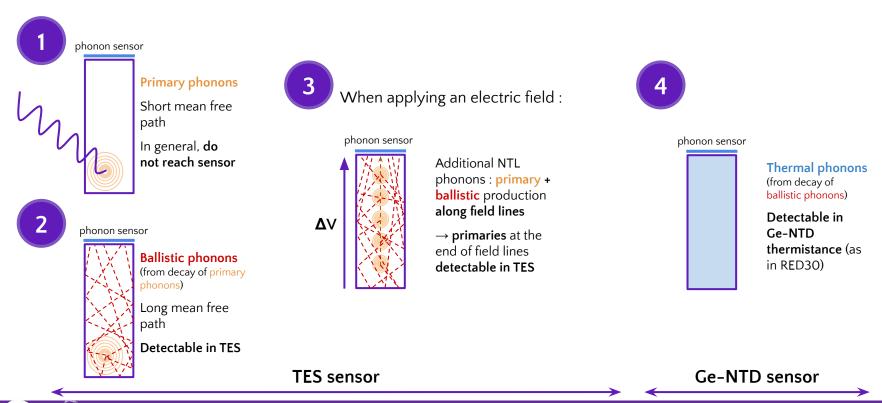
High Voltage loss of Particle Identification

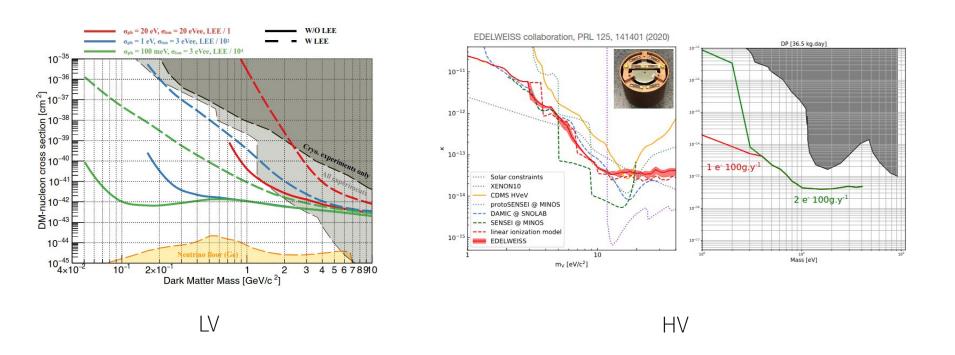






Different kinds of phonons and different sensors



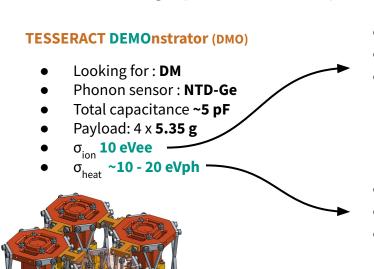


TESSERACT back. model = 10 DRU gamma + other backgrounds from EDW-III



From Ricochet to TESSERACT

Going beyond the Ricochet CryoCube technology



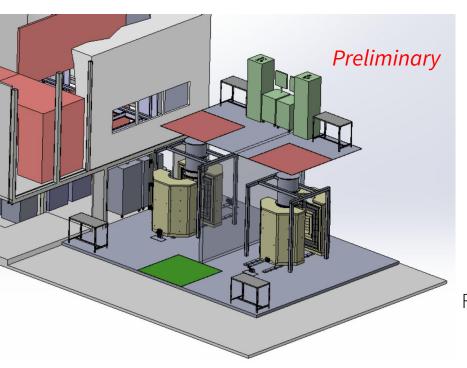
J.Colas

- Reduce the detector volume
- Put the HEMT amplificator at < 1 cm from the electrode</p>
- Optimize the holder, COMSOL driven

- Reduce the detector volume
- Optimize NTD dimension
- Low microphonic holder

TESSERACT: Proposal experiment at LSM

Transition Edge Sensor with Sub-Ev Resolution And Cryogenic Targets



Two cryostats, one experimental design, several targets:

- SPICE (Al₂O₃ and GaAs)
- HeRALD (LHe)
- Ge/Si bolometers









All equipped with new generation TES

Complementary DM sensitivity
Final setup at Laboratoire Souterrain de Modane (2028)





